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Vishay Semiconductors

AUTOMOTIVE

COMPLIANT HALOGEN

FREE

Hyperfast Rectifier, 2 A FRED Pt®

eSMP® Series



Top View

Bottom View

SlimSMAW (DO-221AD)



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 A			
V_{R}	100 V, 200 V			
V _F at I _F	0.69 V			
I _{FSM}	60 A			
t _{rr} (typ.)	15 ns			
T _J max.	175 °C			
Package	SlimSMAW (DO-221AD)			
Circuit configuration	Single			

FEATURES

- Low profile package
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, class 2 whisker test
- Compatible to SOD-128 package case outline
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial, and automotive applications.

MECHANICAL DATA

Case: SlimSMAW (DO-221AD)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse	VS-2EYH01HM3	V		100	V	
voltage	VS-2EYH02HM3	V_{RRM}		200	V	
Average rectified forward current		I _{F(AV)} (1)	T _C = 151 °C	2	Α	
Non-repetitive peak surge current		I _{FSM}	T _J = 25 °C, 10 ms sine pulse wave	60		
Operating junction and storage temperatures		T _J , T _{Stg}		-55 to +175	°C	

Note

(1) Mounted on infinite heatsink

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking VS-2EYH01HM3	V V I 100		100	-	-	
voltage VS-2EYH02HM3	V_{BR}, V_{R}	I _R = 100 μA	200	-	-	V
Forward voltage, per diode	V _F	I _F = 2 A	-	0.86	0.93	
	VF.	I _F = 2 A, T _J = 150 °C	-	0.69	0.75	
Reverse leakage current, per diode	I_	V _R = V _R rated	-	-	2	μΑ
neverse leakage current, per diode	I _R	$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	1	20	
Junction capacitance	C _T	V _R = 200 V	_	12	-	pF

VS-2EYH01HM3, VS-2EYH02HM3

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
	t _{rr}	I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		22	-	
		$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	15	-	ns
Reverse recovery time		I _F = 0.5 A, I _R = 1A, I _{rr} = 0.25 A		-	-	28	
		T _J = 25 °C	$I_F = 2 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 100 \text{ V}$	-	16	-	
		T _J = 125 °C		-	26	-	
Peak recovery current		T _J = 25 °C		-	2.7	-	Λ
	I _{RRM}	RM T 105 %C		-	3.4	-	Α
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	20	-	nC
		T _J = 125 °C		-	43	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount		R _{thJM} ⁽¹⁾	Infinite heatsink	-	12	15	
Thermal resistance, junction to ambient		R _{thJA}	Device mounted on FR4 PCB, 2 oz. standard footprint	-	120	150	°C/W
VS-2EYH01HM3			Case style SlimSMAW (DO-221AD)		2H1		
Marking device	VS-2EYH02HM3		Case style Sill ISWAW (DO-22 IAD)	2H2			

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

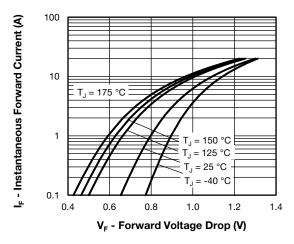


Fig. 1 - Typical Forward Voltage Drop Characteristics

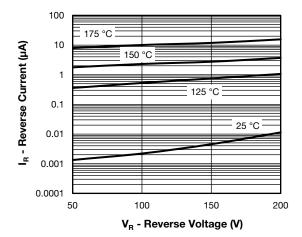


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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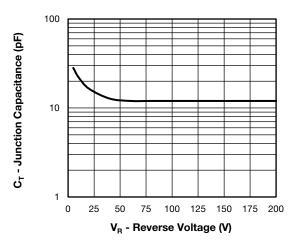


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

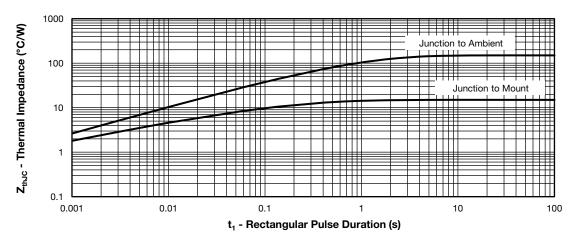


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

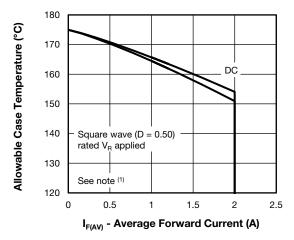


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

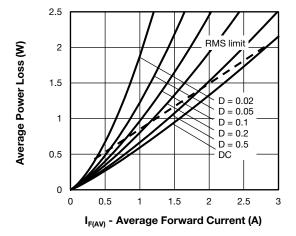


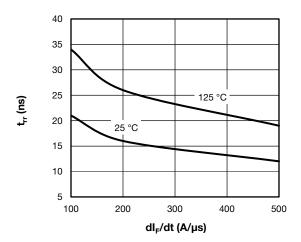
Fig. 6 - Forward Power Loss Characteristics

Note

Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 5); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R

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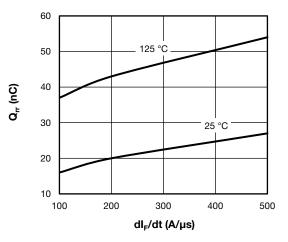
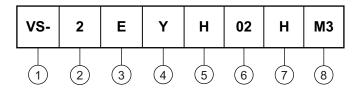


Fig. 8 - Typical Stored Charge vs. dl_F/dt

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (2 = 2 A)

3 - Circuit configuration:

E = single diode

Y = SlimSMAW (DO-221AD)

5 - Process type,

H = hyperfast recovery

Voltage code (02 = 200 V)

7 - H = AEC-Q101 qualified

8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-2EYH01HM3/H	0.033	Н	3500	7"diameter plastic tape and reel			
VS-2EYH01HM3/I	0.033	1	14 000	13"diameter plastic tape and reel			
VS-2EYH02HM3/H	0.033	Н	3500	7"diameter plastic tape and reel			
VS-2EYH02HM3/I	0.033	1	14 000	13"diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96582</u>					
Part marking information	www.vishay.com/doc?95562				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96585				



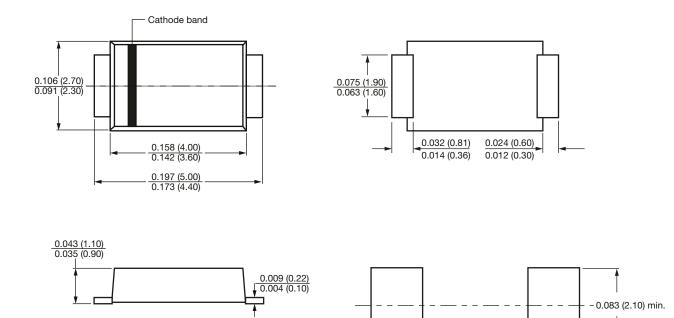
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0.055 (1.40) min.

SlimSMAW (DO-221AD)

DIMENSIONS in inches (millimeters)

SlimSMAW (DO-221AD)



0.055 (1.40) min.

Mounting pad layout

0.118 (3.00) max.

0.228 (5.80) ref.



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